# NSN 5962-01-011-3484

Memory Microcircuit - Page 1 of 1



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# Body Length:

Between 0.750 inches and 0.785 inches

# Body Width:

Between 0.220 inches and 0.280 inches

# **Body Height:**

Between 0.140 inches and 0.180 inches

# **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

# Storage Tempurature Range:

-65.0/+150.0 degrees celsius

# Features Provided:

Hermetically sealed and monolithic and positive outputs and w/enable and programmable and programmed and high speed and w/open collector

# Inclosure Material:

inclosure material.

# Ceramic and glass

### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

10 input

#### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

5.5 volts power source

#### **Time Rating Per Chacteristic:**

65.00 nanoseconds propagation delay time, low to high level output

#### Memory Device Type:

Rom

# Test Data Document:

94990-51-+01508e drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# Terminal Type And Quantity:

16 printed circuit

#### Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

#### Fiig:

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